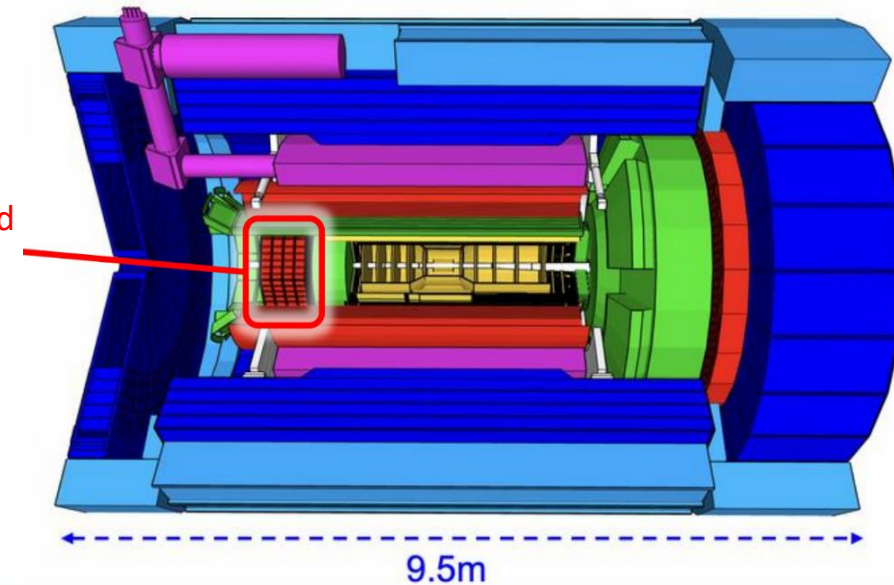


High resolution in the forward region (endcap) can only be achieved with homogeneous materials, such as crystals



- ~3000 PWO crystals
- SiPM readout
- Cooling
- LED monitoring

**Requirements:**

- Energy resolution:  $2\%/\sqrt{E} + (1-3)\%$
- Pion suppression:  $1:10^4$
- Minimum detection energy:  $> 50 \text{ MeV}$

Technology choice: PWO crystals ( $2 \times 2 \text{ cm}^2$ ) with high density SiPM ( $16 \text{ } 3 \times 3 \text{ mm}^2$  or  $4 \text{ } 6 \times 6 \text{ mm}^2$  per crystal)

Will use physics processes/particles to best determine calibration coefficients their evolution with time

➤ **Single electrons:**

- Relies on tracker (calibration, accuracy...)
- May not be possible for all crystals

➤ **Neutral pion decays:  $\pi^0 \rightarrow \gamma \gamma$**

- **Very clear signal – no need of other detectors**
- Invariant mass of  $\pi^0$  used for calibration, but non-linear procedure (2 clusters per event)

➤ **MIPs**

- Wide signal distribution
- Relies on simulation (or independent measurement) for absolute calibration

- Methods successfully used with EMCals at JLab
- Based on NIM A566 (2006) 366

Basic principle:

optimize calibration coefficient to constrain the  $\pi^0$  invariant mass position and minimize its width

$$F = \sum_{i=1}^{N_{events}} (m_i^2 - m_0^2)^2 + 2\lambda \sum_{i=1}^{N_{events}} (m_i^2 - m_0^2)$$

resolution term  
to optimize

constraint  $\langle m_i^2 \rangle = m_0^2$

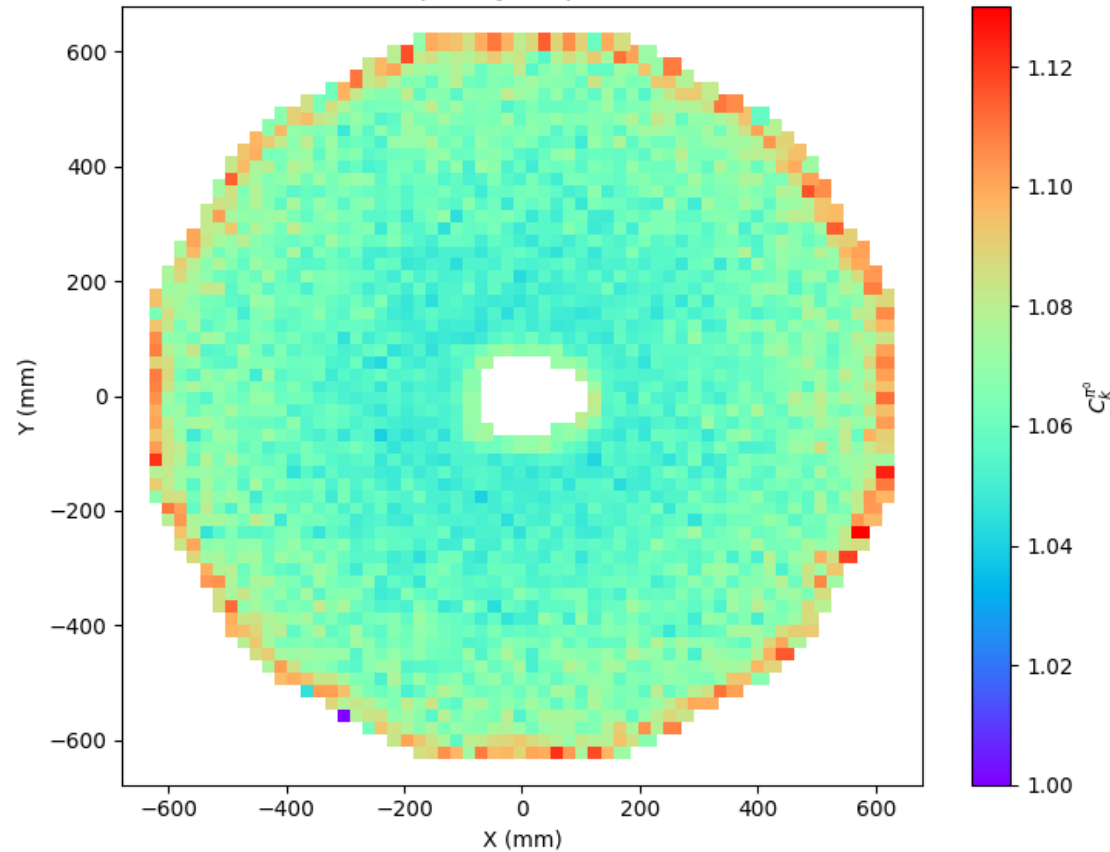
$m_0 = M_\pi = 0.1349766$  GeV

$m_i$ : reconstructed  $M_{\gamma\gamma}$

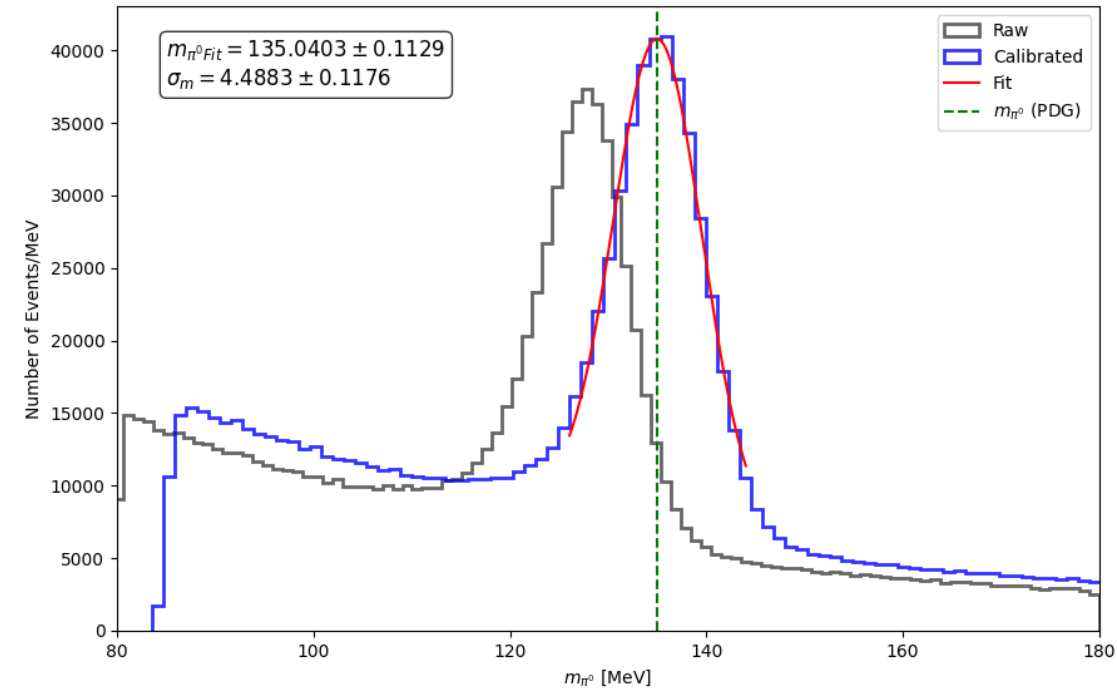
$\lambda$ : Lagrange multiplier

## SIDIS simulation at 18x275 GeV

Calibration coefficients per crystal position (after 20 iterations)

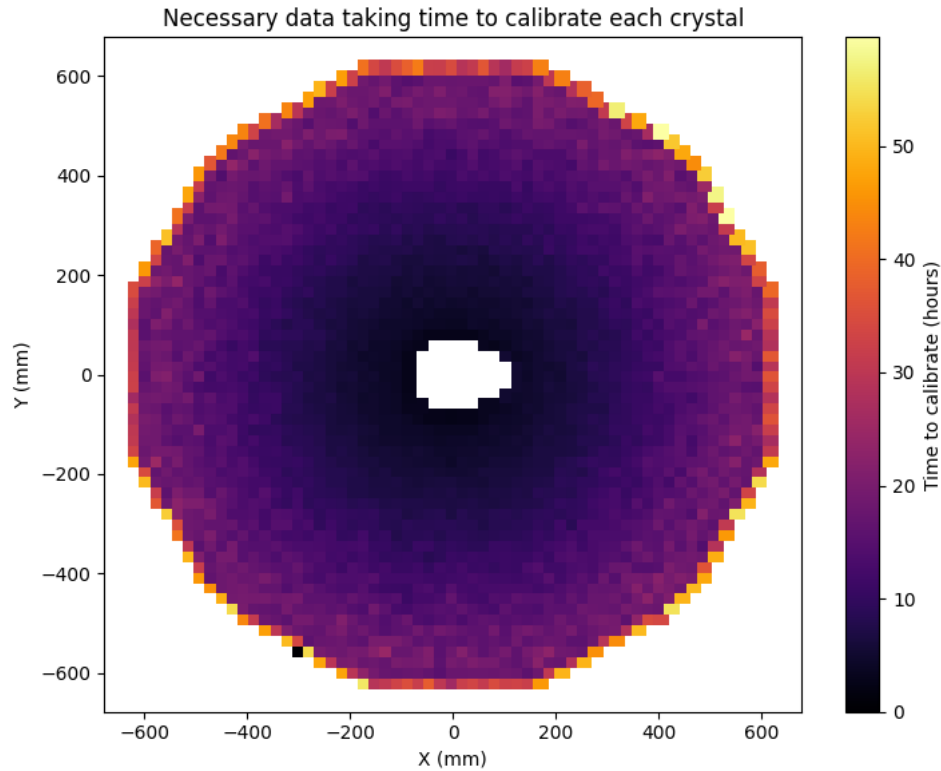


Reconstructed  $\pi^0$  Mass Before and After Calibration (After 15 iterations)

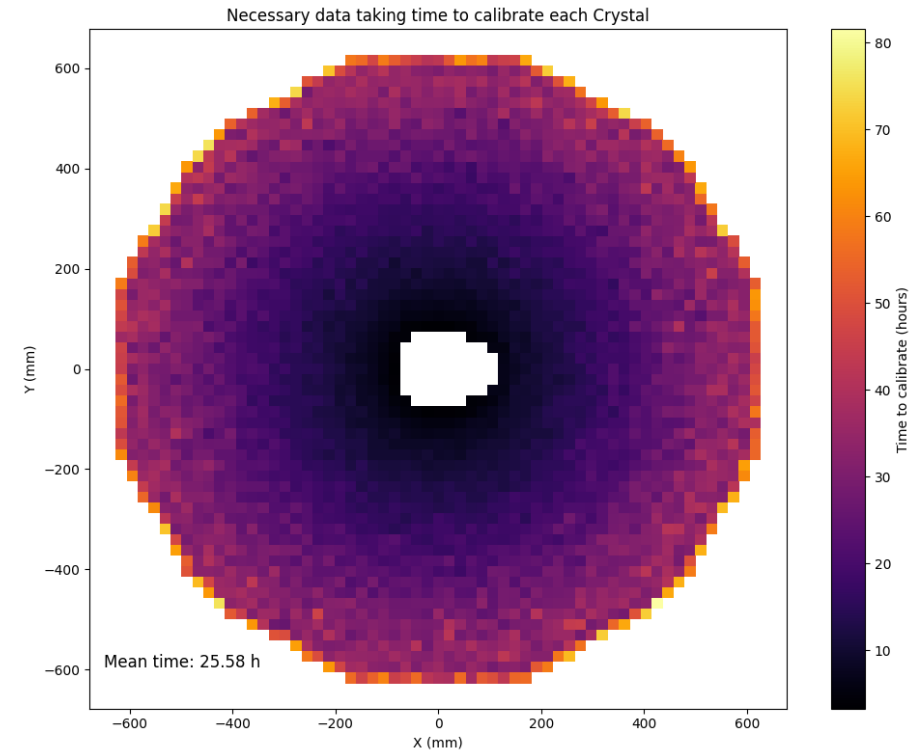


Analysis by Axel Perez Ruiz (IJCLab)

- Number of hours needed for 1000 events/crystal
- SIDIS simulation



18x275 GeV



5x41 GeV

1-2 days of data should be sufficient